January, 2006

# FPDB20PH60



SEMICONDUCTOR®

# FPDB20PH60

#### **Smart Power Module for Front-End Rectifier**

#### **General Description**

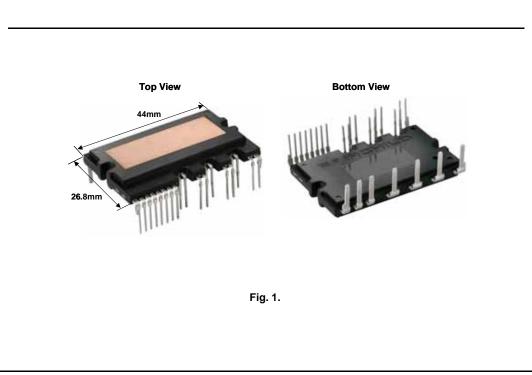
FPDB20PH60 is an advanced smart power module of PFC(Power Factor Correction) that Fairchild has newly developed and designed mainly targeting mid-power application especially for an air conditioners. It combines optimized circuit protection and drive IC matched to high frequency switching IGBTs. System reliability is futher enhanced by the integrated under-voltage lock-out and over-current protection function.

#### Features

- Low thermal resistance due to Al<sub>2</sub>O<sub>3</sub>-DBC substrate
- 600V-20A 2-phase IGBT PWM semi-converter including a drive IC for gate driving and protection
- Typical switching frequency of 20kHz
- Isolation rating of 2500Vrms/min.

#### Applications

• AC 180V ~ 264V single-phase front-end rectifier



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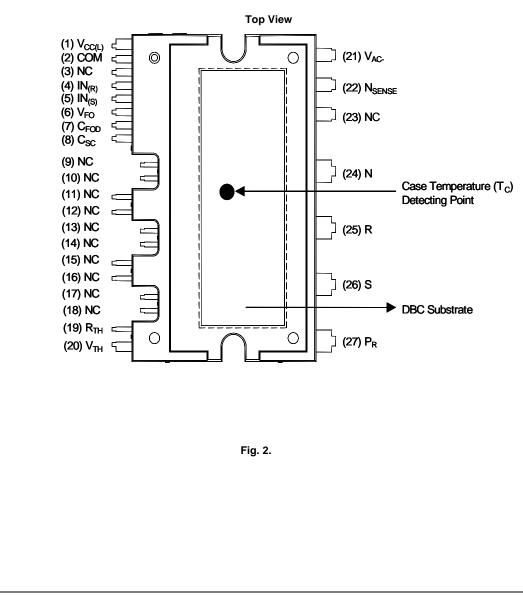
#### **Integrated Power Functions**

• PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

#### Integrated Drive, Protection and System Control Functions

- For IGBTs: Gate drive circuit, Overcurrent circuit protection (OC), Control supply circuit under-voltage (UV) protection
- Fault signaling: Corresponding to a UV fault
- Input interface: 5V CMOS/LSTTL compatible, Schmitt trigger input

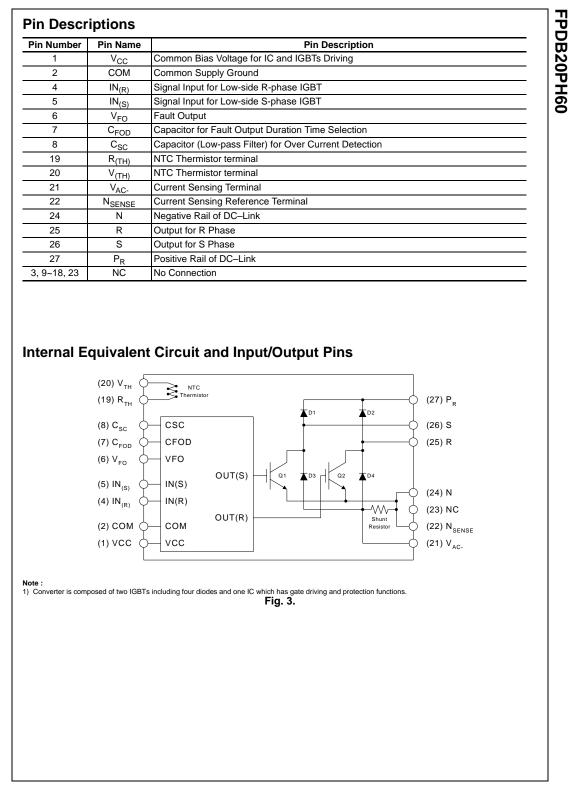
### **Pin Configuration**



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## Absolute Maximum Ratings (T<sub>J</sub> = 25°C, Unless Otherwise Specified) **Converter Part**

Item	Symbol	Condition	Rating	Unit
Supply Voltage	Vi	Applied between R-S	264	V <sub>RMS</sub>
Supply Voltage (Surge)	V <sub>i(Surge)</sub>	Applied between R-S	500	V
Output Voltage	V <sub>PN</sub>	Applied between P- N	450	V
Output Voltage (Surge)	V <sub>PN(Surge)</sub>	Applied between P- N	500	V
Collector-emitter Voltage	V <sub>CES</sub>		600	V
Input Current (100% Load)	li	T <sub>C</sub> < 95°C, V <sub>i</sub> =220V, V <sub>PN</sub> = 390V, V <sub>PWM</sub> =20kHz	12	A
Input Current (125% Load)	I <sub>i(125%)</sub>	T <sub>C</sub> < 95°C, V <sub>i</sub> =220V, V <sub>PN</sub> = 390V, V <sub>PWM</sub> =20kHz, 1min Non-repetitive	15	A
Collector Dissipation	P <sub>C</sub>	T <sub>C</sub> = 25°C per One IGBT	62.5	W
Power Rating of Shunt Resistor	P <sub>RSH</sub>	T <sub>C</sub> < 125°C	1.5	W
Operating Junction Temperature	TJ	(Note 1)	-20 ~ 125	°C

Note

 The maximum junction temperature rating of the power chips integrated within the SPM is 150 °C(@T<sub>C</sub> ≤ 100°C). However, to insure safe operation of the SPM, the average junction temperature should be limited to T<sub>J(ave)</sub> ≤ 125°C (@T<sub>C</sub> ≤ 100°C)

#### **Control Part**

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V <sub>CC</sub>	Applied between V <sub>CC</sub> - COM	20	V
Input Signal Voltage	V <sub>IN</sub>	Applied between IN - COM	-0.3~5.5	V
Fault Output Supply Voltage	V <sub>FO</sub>	Applied between V <sub>FO</sub> - COM	-0.3~V <sub>CC</sub> +0.3	V
Fault Output Current	I <sub>FO</sub>	Sink Current at V <sub>FO</sub> Pin	5	mA
Current Sensing Input Voltage	V <sub>SC</sub>	Applied between C <sub>SC</sub> - COM	-0.3~V <sub>CC</sub> +0.3	V

#### **Total System**

Item	Symbol	Condition	Rating	Unit
Module Case Operation Temperature	т <sub>с</sub>		-20 ~ 100	°C
Storage Temperature	T <sub>STG</sub>		-40 ~ 125	°C
Isolation Voltage	100	60Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V <sub>rms</sub>

#### **Thermal Resistance**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal	R <sub>θ(j-c)Q</sub>	IGBT	-	-	1.6	°C/W
Resistance	$R_{\theta(j-c)HD}$	High-side diode	-	-	2.4	°C/W
(Referenced to chip center)	$R_{\theta(j-c)LD}$	Low-side diode	-	-	1.9	°C/W

Note :

2. For the measurement point of case temperature(T<sub>C</sub>), please refer to Fig. 2.

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### Electrical Characteristics (T<sub>J</sub> = 25°C, Unless Otherwise Specified) **Converter Part**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
IGBT saturation voltage	V <sub>CE(sat)</sub>	V <sub>CC</sub> =15V, V <sub>IN</sub> = 5V; I <sub>C</sub> =20A	-	2.4	3.0	V
High-side diode voltage	V <sub>FH</sub>	I <sub>F</sub> = 20A	-	1.9	2.7	V
Low-side diode voltage	V <sub>FL</sub>	I <sub>F</sub> = 20A	-	1.1	1.5	V
Switching Times	t <sub>ON</sub>	$V_{PN} = 400V, V_{CC} = 15V, I_C = 20A$ $V_{IN} = 0V \leftrightarrow 5V$ , Inductive Load (Note 3)	-	690	-	ns
	t <sub>C(ON)</sub>		-	510	-	ns
	t <sub>OFF</sub>		-	450	-	ns
	t <sub>C(OFF)</sub>		-	120	-	ns
	t <sub>rr</sub>		-	50	-	ns
	I <sub>rr</sub>		-	2	-	Α
Current sensing resistor	R <sub>SENSE</sub>		3.6	4.0	4.4	mΩ
Collector - emitter Leakage Current	I <sub>CES</sub>	V <sub>CE</sub> = V <sub>CES</sub>	-	-	250	μΑ

Note
3. t<sub>ONF</sub> and t<sub>OFF</sub> include the propagation delay time of the internal drive IC. t<sub>C(ON)</sub> and t<sub>C(OFF)</sub> are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

#### **Control Part**

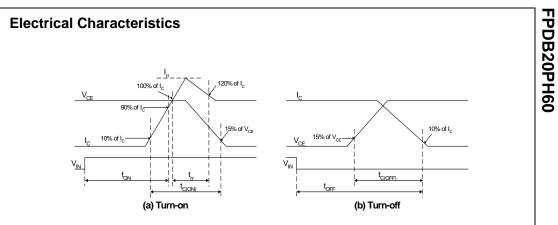
Item	Symbol	C	ondition	Min.	Тур.	Max.	Unit
Quiescent $V_{\mbox{CC}}$ Supply Current	IQCCL	V <sub>CC</sub> = 15V, IN = 0V	V <sub>CC</sub> - COM	-	-	26	mA
Fault Output Voltage	V <sub>FOH</sub>	V <sub>SC</sub> = 0V, V <sub>FO</sub> Circui	t: 4.7kΩ to 5V Pull-up	4.5	-	-	V
	V <sub>FOL</sub>	V <sub>SC</sub> = 1V, V <sub>FO</sub> Circui	t: 4.7kΩ to 5V Pull-up	-	-	0.8	V
Over Current Trip Level	V <sub>SC(ref)</sub>	V <sub>CC</sub> = 15V		0.45	0.5	0.55	V
Supply Circuit Under-	UV <sub>CCD</sub>	Detection Level		10.7	11.9	13.0	V
Voltage Protection	UV <sub>CCR</sub>	Reset Level		11.2	12.4	13.2	V
Fault-out Pulse Width	t <sub>FOD</sub>	C <sub>FOD</sub> = 33nF (Note 4)		1.4	1.8	2.0	ms
ON Threshold Voltage	V <sub>IN(ON)</sub>	Applied between IN - COM		3.0	-	-	V
OFF Threshold Voltage	V <sub>IN(OFF)</sub>			-	-	0.8	V
Resistance of Thermistor	R <sub>TH</sub>	@ T <sub>C</sub> = 25°C (Note F	Fig. 9)	-	50	-	kΩ
		@ T <sub>C</sub> = 80°C (Note F	-ig. 9)	-	5.76	-	kΩ

Note 4. The fault-out pulse width  $t_{FOD}$  depends on the capacitance value of  $C_{FOD}$  according to the following approximate equation :  $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD}[F]$ 

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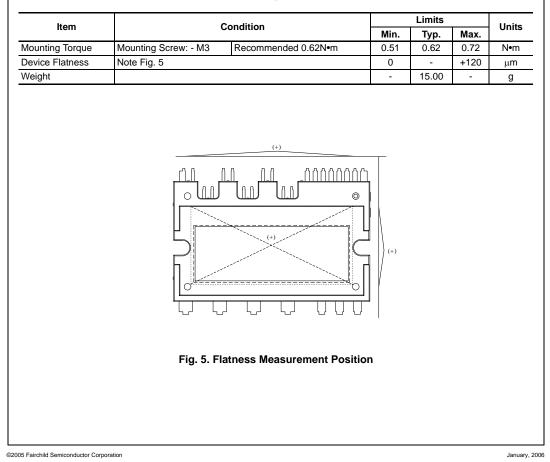
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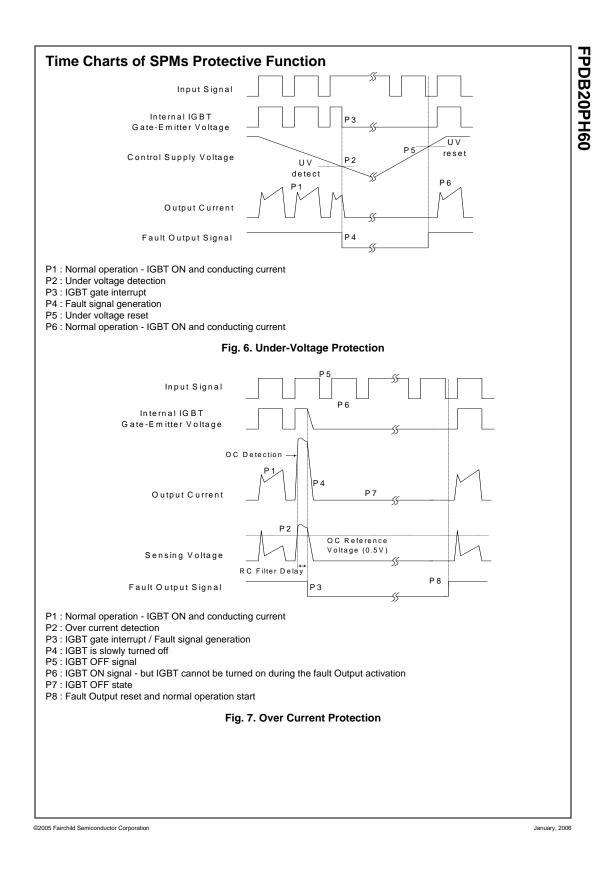
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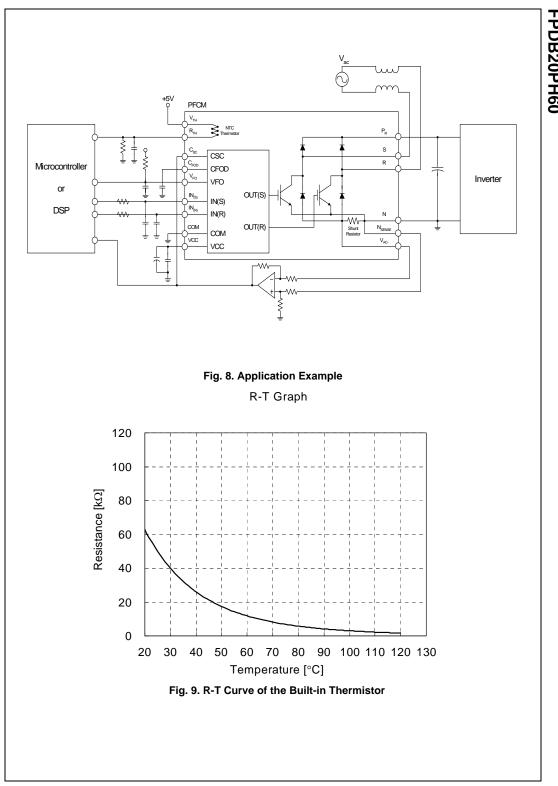
#### Fig. 4. Switching Time Definition

# **Mechanical Characteristics and Ratings**



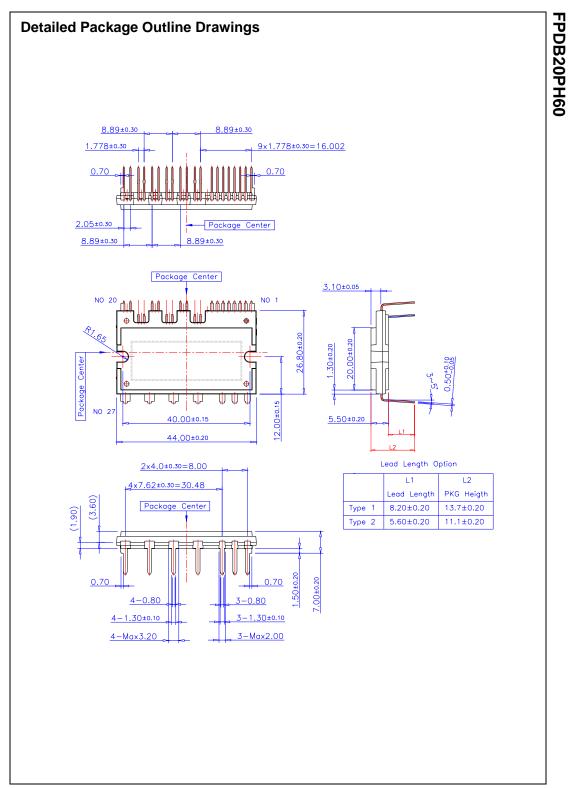


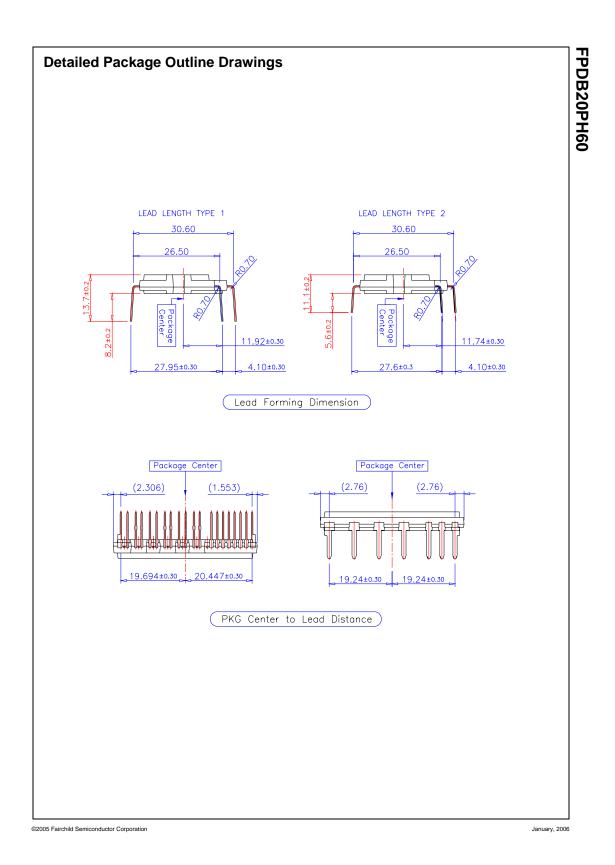
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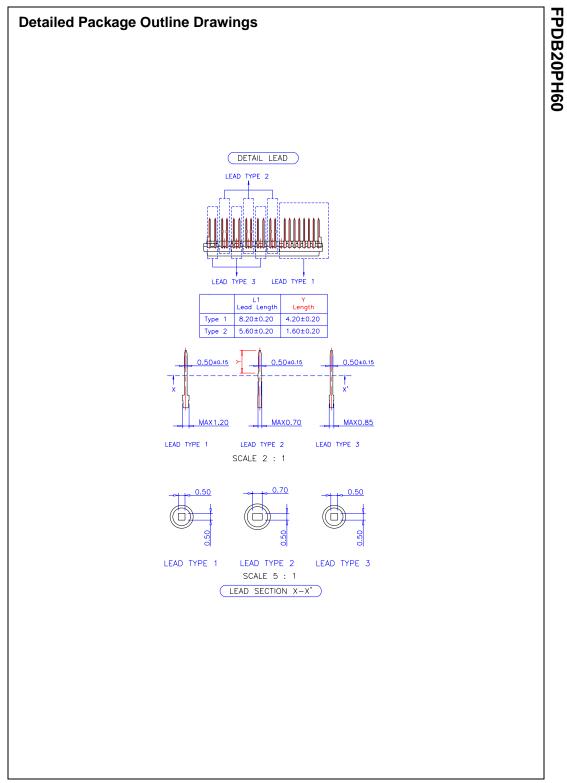


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